

Dual Pipeline Register

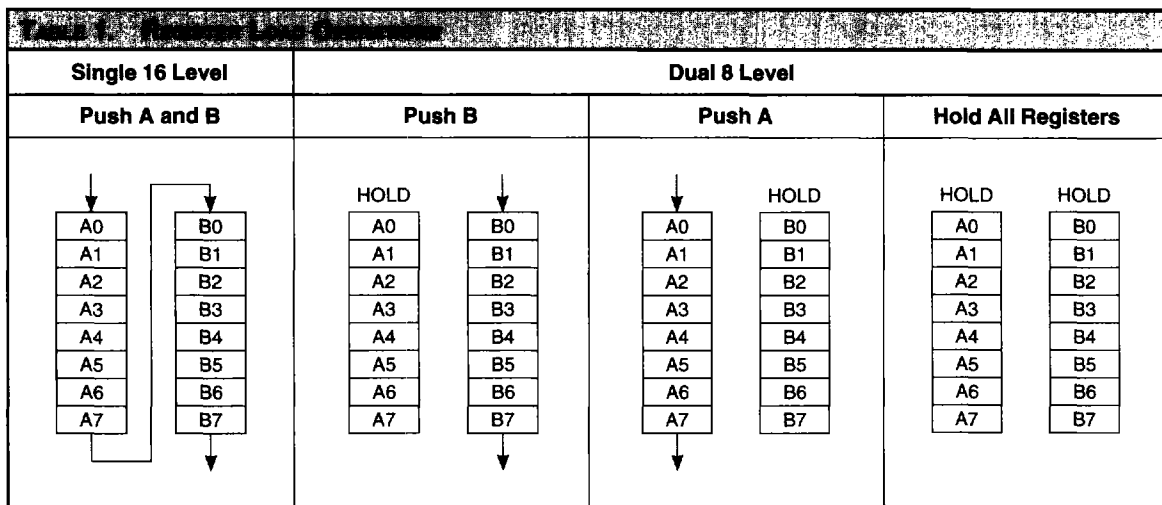


Table 2. Input/Output

Mnemonics	Inputs		Description
	I1	I0	
Shift	0	0	Push A and B
LDB	0	1	Push B
LDA	1	0	Push A
HLD	1	1	Hold All Registers

Table 3. Output Binary

S3	S2	S1	S0	Y7-0
0	0	0	0	A0
0	0	0	1	A1
0	0	1	0	A2
0	0	1	1	A3
0	1	0	0	A4
0	1	0	1	A5
0	1	1	0	A6
0	1	1	1	A7
1	0	0	0	B0
1	0	0	1	B1
1	0	1	0	B2
1	0	1	1	B3
1	1	0	0	B4
1	1	0	1	B5
1	1	1	0	B6
1	1	1	1	B7

Maximum Ratings Above which useful life may be impaired (Notes 1, 2, 3, 6)

Storage temperature	–65°C to +150°C
Operating ambient temperature	–55°C to +125°C
V _{CC} supply voltage with respect to ground	–0.5 V to +7.0 V
Input signal with respect to ground	–3.0 V to +7.0 V
Signal applied to high impedance output	–3.0 V to +7.0 V
Output current into low outputs	25 mA
Latchup current	> 400 mA

Operating Conditions To meet specified electrical and switching characteristics

Mode	Temperature Range (Ambient)	Supply Voltage
Active Operation, Commercial	0°C to +70°C	4.75 V ≤ V _{CC} ≤ 5.25 V
Active Operation, Military	–55°C to +125°C	4.50 V ≤ V _{CC} ≤ 5.50 V

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Electrical Characteristics Over Operating Conditions (Note 4)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
V _{OH}	Output High Voltage	V _{CC} = Min., I _{OH} = –12 mA	2.4			V
V _{OL}	Output Low Voltage	V _{CC} = Min., I _{OL} = 24 mA			0.5	V
V _{IH}	Input High Voltage		2.0		V _{CC}	V
V _{IL}	Input Low Voltage	(Note 3)	0.0		0.8	V
I _{IX}	Input Current	Ground ≤ V _{IN} ≤ V _{CC} (Note 12)			±20	μA
I _{OZ}	Output Leakage Current	Ground ≤ V _{OUT} ≤ V _{CC} (Note 12)			±20	μA
I _{CC1}	V _{CC} Current, Dynamic	(Notes 5, 6)		10	35	mA
I _{CC2}	V _{CC} Current, Quiescent	(Note 7)			1.0	mA

SWITCHING CHARACTERISTICS

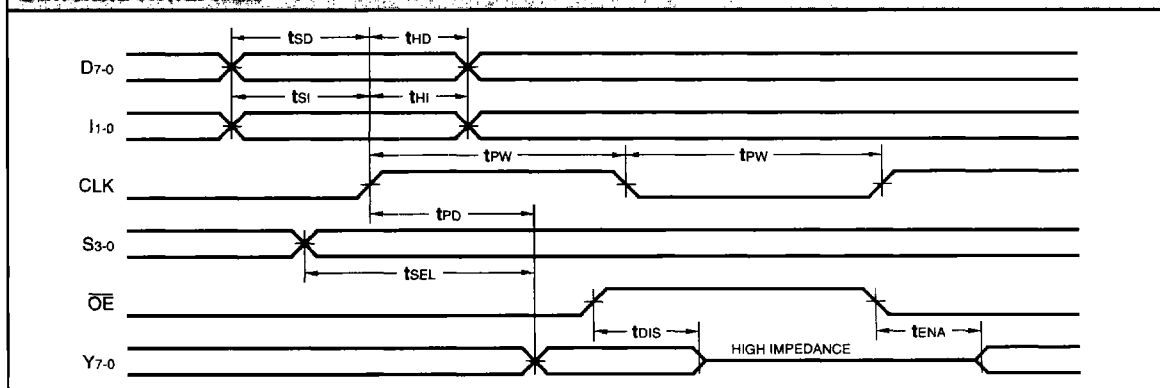
COMMERCIAL OPERATING RANGE (0°C to +70°C) Notes 9, 10 (ns)

Symbol	Parameter	L29C525-			
		20		15	
		Min	Max	Min	Max
t _{PD}	Clock to Output Delay		20		15
t _{SEL}	Select to Output Delay		20		15
t _{PW}	Clock Pulse Width	12		10	
t _{SD}	Data Setup Time	7		5	
t _{HD}	Data Hold Time	0		0	
t _{SI}	Instruction Setup Time	7		5	
t _{HI}	Instruction Hold Time	2		2	
t _{ENA}	Three-State Output Enable Delay (Note 11)		15		15
t _{DIS}	Three-State Output Disable Delay (Note 11)		13		13

MILITARY OPERATING RANGE (-55°C to +125°C) Notes 9, 10 (ns)

Symbol	Parameter	L29C525-			
		25		20	
		Min	Max	Min	Max
t _{PD}	Clock to Output Delay		25		20
t _{SEL}	Select to Output Delay		25		20
t _{PW}	Clock Pulse Width	12		12	
t _{SD}	Data Setup Time	7		7	
t _{HD}	Data Hold Time	2		2	
t _{SI}	Instruction Setup Time	7		7	
t _{HI}	Instruction Hold Time	2		2	
t _{ENA}	Three-State Output Enable Delay (Note 11)		15		15
t _{DIS}	Three-State Output Disable Delay (Note 11)		13		13

SWITCHING WAVEFORMS



NOTES

1. Maximum Ratings indicate stress specifications only. Functional operation of these products at values beyond those indicated in the Operating Conditions table is not implied. Exposure to maximum rating conditions for extended periods may affect reliability.

2. The products described by this specification include internal circuitry designed to protect the chip from damaging substrate injection currents and accumulations of static charge. Nevertheless, conventional precautions should be observed during storage, handling, and use of these circuits in order to avoid exposure to excessive electrical stress values.

3. This device provides hard clamping of transient undershoot and overshoot. Input levels below ground or above VCC will be clamped beginning at -0.6 V and VCC + 0.6 V. The device can withstand indefinite operation with inputs in the range of -0.5 V to +7.0 V. Device operation will not be adversely affected, however, input current levels will be well in excess of 100 mA.

4. Actual test conditions may vary from those designated but operation is guaranteed as specified.

5. Supply current for a given application can be accurately approximated by:

$$NCV^2F$$

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where

- N = total number of device outputs
- C = capacitive load per output
- V = supply voltage
- F = clock frequency

6. Tested with all outputs changing every cycle and no load, at a 5 MHz clock rate.

7. Tested with all inputs within 0.1 V of VCC or Ground, no load.

8. These parameters are guaranteed but not 100% tested.

9. AC specifications are tested with input transition times less than 3 ns, output reference levels of 1.5 V (except tDIS test), and input levels of nominally 0 to 3.0 V. Output loading may be a resistive divider which provides for specified IOH and IOL at an output voltage of VOH min and VOL max respectively. Alternatively, a diode bridge with upper and lower current sources of IOH and IOL respectively, and a balancing voltage of 1.5 V may be used. Parasitic capacitance is 30 pF minimum, and may be distributed.

This device has high-speed outputs capable of large instantaneous current pulses and fast turn-on/turn-off times. As a result, care must be exercised in the testing of this device. The following measures are recommended:

a. A 0.1 μ F ceramic capacitor should be installed between VCC and Ground leads as close to the Device Under Test (DUT) as possible. Similar capacitors should be installed between device VCC and the tester common, and device ground and tester common.

b. Ground and VCC supply planes must be brought directly to the DUT socket or contactor fingers.

c. Input voltages should be adjusted to compensate for inductive ground and VCC noise to maintain required DUT input levels relative to the DUT ground pin.

10. Each parameter is shown as a minimum or maximum value. Input requirements are specified from the point of view of the external system driving the chip. Setup time, for example, is specified as a minimum since the external system must supply at least that much time to meet the worst-case requirements of all parts. Responses from the internal circuitry are specified from the point of view of the device. Output delay, for example, is specified as a maximum since worst-case operation of any device always provides data within that time.

11. For the tENA test, the transition is measured to the 1.5 V crossing point with datasheet loads. For the tDIS test, the transition is measured to the ± 200 mV level from the measured steady-state output voltage with ± 10 mA loads. The balancing voltage, VTH, is set at 3.5 V for Z-to-0 and 0-to-Z tests, and set at 0 V for Z-to-1 and 1-to-Z tests.

12. These parameters are only tested at the high temperature extreme, which is the worst case for leakage current.

FIGURE A. OUTPUT LOADING CIRCUIT

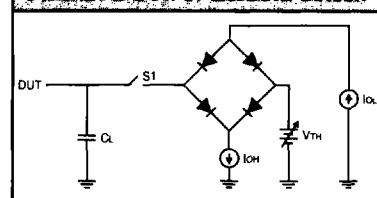
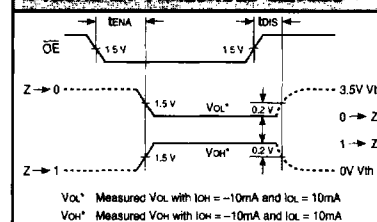
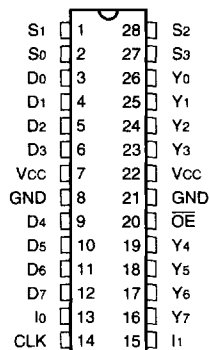


FIGURE B. THRESHOLD LEVELS

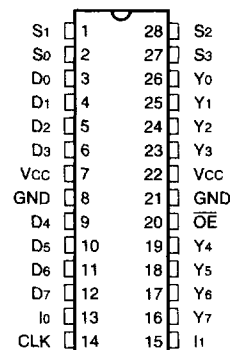


ORDERING INFORMATION

28-pin — 0.3" wide



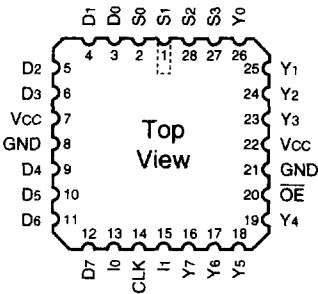
28-pin — 0.4" wide



Speed	Plastic DIP (P10)	Ceramic DIP (C5)	Ceramic DIP (C10)
0°C to +70°C — Commercial Screening			
20 ns	L29C525PC20	L29C525CC20	L29C525IC20
15 ns	L29C525PC15	L29C525CC15	L29C525IC15
-55°C to +125°C — Commercial Screening			
25 ns		L29C525CM25	L29C525IM25
20 ns		L29C525CM20	L29C525IM20
-55°C to +125°C — MIL-STD-883 COMPLIANT			
25 ns		L29C525CMB25	L29C525IMB25
20 ns		L29C525CMB20	L29C525IMB20

ORDERING INFORMATION

28-pin



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Speed	Plastic J-Lead Chip Carrier (J4)	Ceramic Leadless Chip Carrier (K1)	
	0°C to +70°C — Commercial Standard		
20 ns 15 ns	L29C525JC20 L29C525JC15		
	-55°C to +125°C — Commercial Standard		
	-55°C to +125°C — MIL-STD-883C Class B		
25 ns 20 ns		L29C525KMB25 L29C525KMB20	